

TECHNICAL DATA DATA SHEET 363, REV. B

THREE PHASE FULL WAVE BRIDGE RECTIFIER ASSEMBLY

DESCRIPTION: A 200 VOLT, 5.5 AMP, 5000/150 NANOSECOND THREE PHASE BRIDGE RECTIFIER ASSEMBLY.

RATING	CONDITIONS	MIN	TYP	MAX	UNIT
Peak Inverse Voltage (PIV)	-	-	-	200	Vdc
Average DC Output	T _C = 55 °C	-	-	5.5	Amps
Current (T_c = Case Temp) (I_o)	$T_{\rm C} = 100 {}^{\rm o}{\rm C}$			4.0	
(10)	T _C = 125 °C			2.75	
Average DC Output	$T_A = 25 ^{\circ}C$	-	-	2.5	Amps
Current Ambient Temp.	$T_A = 55^{\circ}c$			2.0	
(no heat sink) (I _o)	$T_{A} = 100^{\circ} c$			1.3	
Peak Single Cycle Surge Current (I _{FSM})	t _p = 8.3 ms Single Half Cycle Sine Wave, Superimposed On Rated Load	-	-	50	Amps(pk)
Peak Recurring Surge Current (I _{FRM})	T _A = 25 °C	-	-	15	Amps
Operating and Storage Temp. (T _{op} & T _{stg})	-	-55	-	+150	°C
Maximum Forward Voltage (V _f)	I _f = 3.0A (300 μsec pulse, duty cycle < 2%)	-	-	1.4	Volts
Maximum Instantaneous	$T_A = 25^\circ C$	-	-	2.0	μAmps
Reverse Current At Rated (PIV)	T _A = 100° C			50	
Reverse Recovery Time (t _{rr}) S6A320 S6A320FR	I _f = 0.5A, I _r = 1.0A, I _{rr} = 0.25A	-	-	5000 250	nsec
Thermal Resistance (θ_{JL})	-	-	-	4.0	°C/W

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SENSITRON TECHNICAL DATA DATA SHEET 363, REV. A

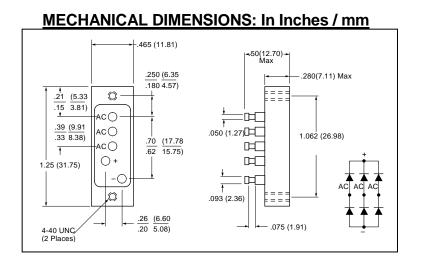


FIG. 409

Note: Case finish - Black Anodized

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